



DUAL CHANNEL ILD621/621GB QUAD CHANNEL ILQ621/621GB

Multi-Channel Phototransistor Optocoupler

FEATURES

- Alternate Source to TLP621-2/-4 and TLP621GB-2/-4
- Current Transfer Ratio (CTR) at $I_F = 5.0$ mA
ILD/Q621: 50% Min.
ILD/Q621GB: 100% Min.
- Saturated Current Transfer Ratio (CTR_{SAT}) at $I_F = 1.0$ mA
ILD/Q621: 60% Typ.
ILD/Q621GB: 30% Min.
- High Collector-Emitter Voltage, $BV_{CEO} = 70$ V
- Dual and Quad Packages Feature:
 - Reduced Board Space
 - Lower Pin and Parts Count
 - Better Channel to Channel CTR Match
 - Improved Common Mode Rejection
- Field-Effect Stable by TRIOS (TRANSPARENT IO Shield)
- Isolation Test Voltage from Double Molded Package, 5300 V_{RMS}
- Underwriters Lab File #E52744
- VDE 0884 Available with Option 1

Maximum Ratings (Each Channel)

Emitter

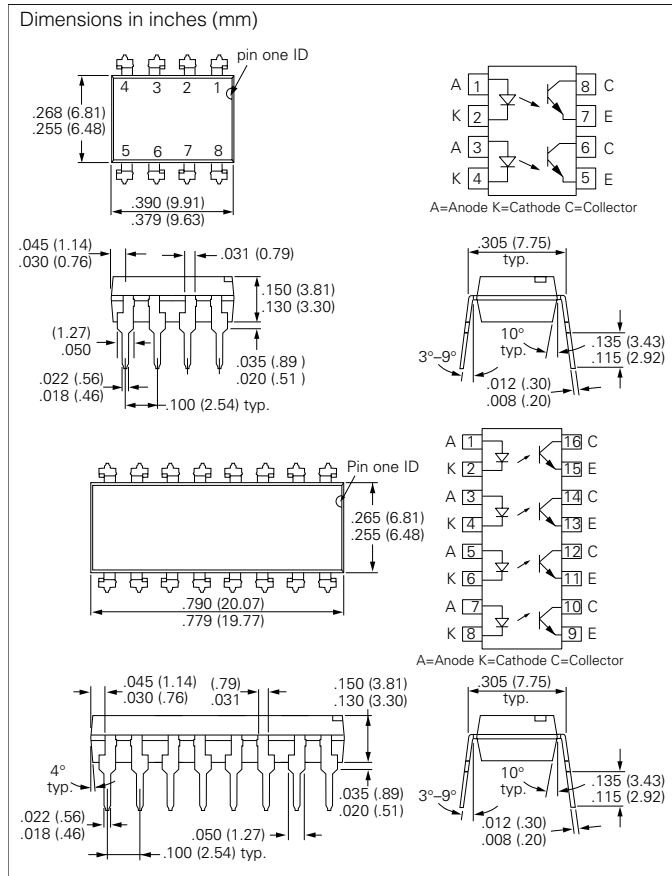
Reverse Voltage	6.0 V
Forward Current	60 mA
Surge Current	1.5 A
Power Dissipation	100 mW
Derate from 25°C	1.33 mW/°C

Detector

Collector-Emitter Reverse Voltage	70 V
Collector Current	50 mA
Collector Current (t < 1.0 ms)	100 mA
Power Dissipation	150 mW
Derate from 25°C	-2.0 mW/°C

Package

Isolation Test Voltage	
(t=1.0 sec.)	5300 V_{RMS}
Package Dissipation ILD620/GB	400 mW
Derate from 25°C	5.33 mW/°C
Package Dissipation ILQ620/GB	500 mW
Derate from 25°C	6.67 mW/°C
Creepage	≥7.0 mm
Clearance	≥7.0 min
Isolation Resistance	
$V_{IO} = 500$ V, $T_A = 25^\circ\text{C}$	≥10 ¹² Ω
$V_{IO} = 500$ V, $T_A = 100^\circ\text{C}$	≥10 ¹¹ Ω
Storage Temperature	-55°C to +150°C
Operating Temperature	-55°C to +100°C
Junction Temperature	100°C
Soldering Temperature	
(2.0 mm from case bottom)	260°C



DESCRIPTION

The ILD/Q621 and ILD/Q621GB are multi-channel phototransistor optocouplers that use GaAs IRLED emitters and high gain NPN silicon phototransistors. These devices are constructed using over/under leadframe optical coupling and double molded insulation technology. This assembly process offers a withstand test voltage of 7500 VDC.

The ILD/Q621GB is well suited for CMOS interfacing given the CTR_{CESat} of 30% minimum at I_F of 1.0 mA. High gain linear operation is guaranteed by a minimum CTR_{CE} of 100% at 5.0 mA. The ILD/Q621 has a guaranteed CTR_{CE} of 50% minimum at 5.0 mA. The TRANSPARENT IO Shield insures stable DC gain in applications such as power supply feedback circuits, where constant DC V_{IO} voltages are present.

Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Emitter						
Forward Voltage	V_F	1.0	1.15	1.3	V	$I_F=10\text{ mA}$
Reverse Current	I_R	—	0.01	10	μA	$V_R=6.0\text{ V}$
Capacitance	C_O	—	40	—	pF	$V_F=0\text{ V}$, $f=1.0\text{ MHz}$
Thermal Resistance, Junction to Lead	R_{THJL}	—	750	—	K/W	—
Detector						
Capacitance	C_{CE}	—	6.8	—	pF	$V_{CE}=5.0\text{ V}$, $f=1.0\text{ MHz}$
Collector-Emitter Leakage Current	I_{CEO}	—	10	100	nA	$V_{CE}=24\text{ V}$
Collector-Emitter Leakage Current	I_{CEO}	—	2.0	50	μA	$T_A=85^\circ\text{C}$, $V_{CE}=24\text{ V}$
Thermal Resistance, Junction to Lead	R_{THJL}	—	500	—	K/W	—
Package Transfer Characteristics						
Channel/Channel CTR Match	CTR _X /CTR _Y	1 to 1	—	3 to 1	—	$I_F=5.0\text{ mA}$, $V_{CE}=5.0\text{ V}$
ILD/Q621						
Saturated Current Transfer Ratio	CTR _{CEsat}	—	60	—	%	$I_F=1.0\text{ mA}$, $V_{CE}=0.4\text{ V}$
Current Transfer Ratio	CTR _{CE}	50	80	600	%	$I_F=5.0\text{ mA}$, $V_{CE}=5.0\text{ V}$
Collector-Emitter Saturation Voltage	V_{CEsat}	—	—	0.4	V	$I_F=8.0\text{ mA}$, $I_{CE}=2.4\text{ mA}$
ILD/Q621GB						
Saturated Current Transfer Ratio	CTR _{CEsat}	30	—	—	%	$I_F=1.0\text{ mA}$, $V_{CE}=0.4\text{ V}$
Current Transfer Ratio (Collector-Emitter)	CTR _{CE}	100	200	600	%	$I_F=5.0\text{ mA}$, $V_{CE}=5.0\text{ V}$
Collector-Emitter Saturation Voltage	V_{CEsat}	—	—	0.4	V	$I_F=1.0\text{ mA}$, $I_{CE}=0.2\text{ mA}$
Isolation and Insulation						
Common Mode Rejection, Output High	CMH	—	5000	—	V/ μs	$V_{CM}=50\text{ V}_{P,P}$, $R_L=1.0\text{ k}\Omega$, $I_F=0\text{ mA}$
Common Mode Rejection, Output Low	CML	—	5000	—	V/ μs	$V_{CM}=50\text{ V}_{P,P}$, $R_L=1.0\text{ k}\Omega$, $I_F=10\text{ mA}$
Common Mode Coupling Capacitance	C_{CM}	—	0.01	—	pF	—
Package Capacitance	C_{I-O}	0.8	—	—	pF	$V_{IO}=0\text{ V}$, $f=1.0\text{ MHz}$
Insulation Resistance	R_S	10^{12}	—	—	Ω	$V_{IO}=500\text{ V}$, $T_A=25^\circ\text{C}$
Channel to Channel Insulation	—	500	—	—	VAC	—

Switching Times

Figure 1. Non-saturated switching timing

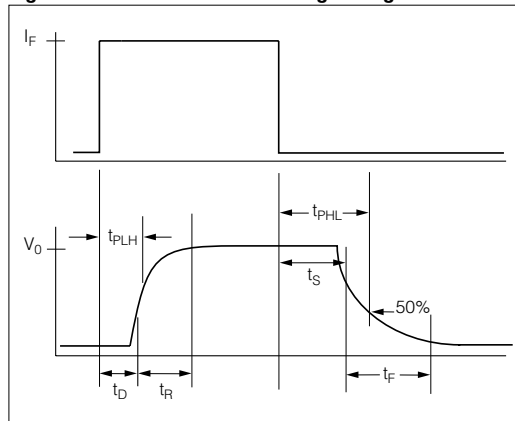
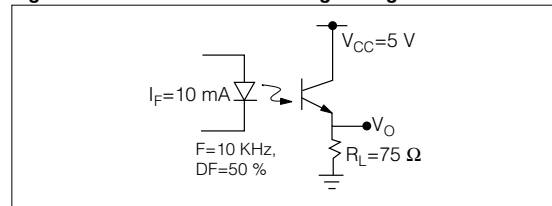


Figure 2. Non-saturated switching timing



Characteristic	Symbol	Typ.	Unit	Test Condition
On Time	t_{ON}	3.0	μs	$I_F=\pm 10\text{ mA}$ $V_{CC}=5.0\text{ V}$ $R_L=75\ \Omega$ 50% of V_{PP}
Rise Time	t_r	2.0		
Off Time	t_{OFF}	2.3		
Fall Time	t_f	2.0		
Propagation H-L	t_{PHL}	1.1		
Propagation L-H	t_{PLH}	2.5		

Figure 3. Saturated switching timing

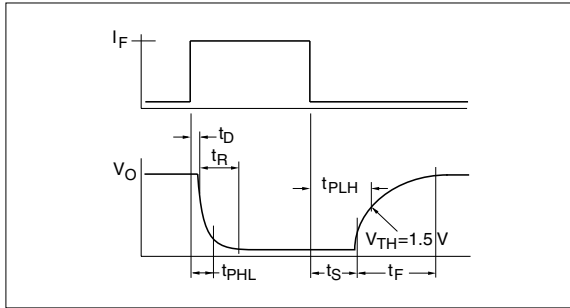
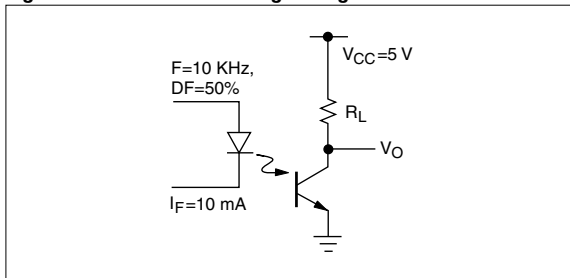


Figure 4. Saturated switching timing



Characteristic	Symbol	Typ.	Unit	Test Condition
On Time	t_{ON}	4.3	μs	$I_F = \pm 10 \text{ mA}$ $V_{CC} = 5.0 \text{ V}$ $R_L = 1.0 \text{ K}\Omega$ $V_{TH} = 1.5 \text{ V}$
Rise Time	t_r	2.8		
Off Time	t_{OFF}	2.5		
Fall Time	t_f	11		
Propagation H-L	t_{pHL}	2.6		
Propagation L-H	t_{pLH}	7.2		

Figure 5. Maximum LED current versus ambient temperature

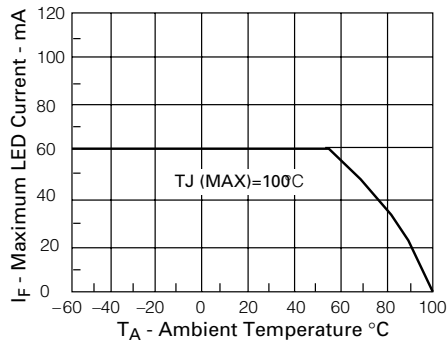


Figure 6. Maximum LED power dissipation

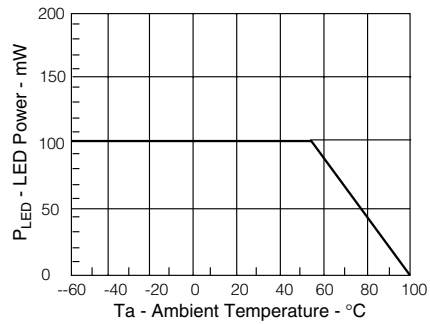


Figure 7. Forward voltage versus forward current

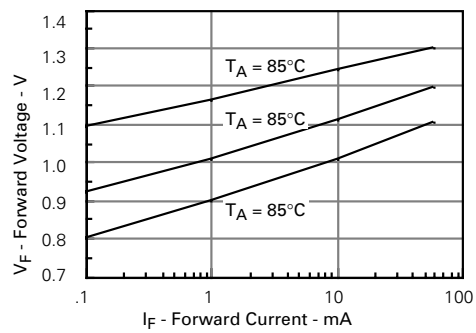


Figure 8. Collector-emitter current versus temperature and LED current

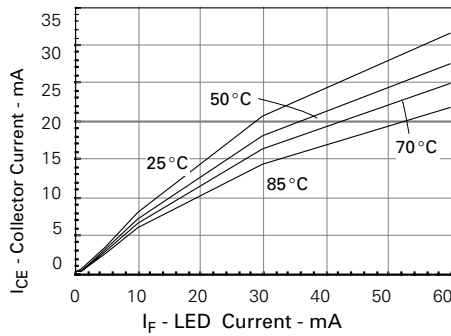


Figure 9. Collector-emitter leakage versus temperature

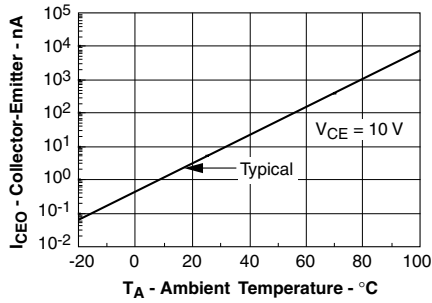


Figure 10. Propagation delay versus collector load resistor

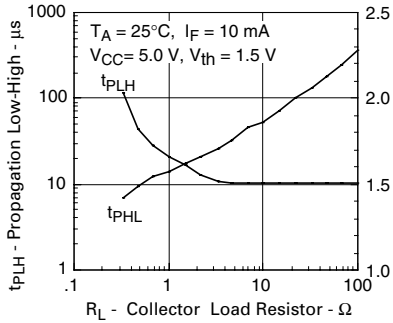


Figure 11. Maximum detector power dissipation

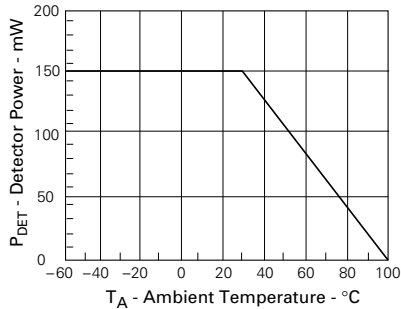


Figure 12. Maximum collector current versus collector voltage

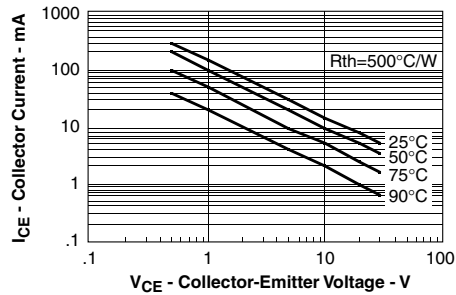


Figure 13. Normalization factor for non-saturated and saturated CTR $T_A=50^\circ\text{C}$ versus I_F

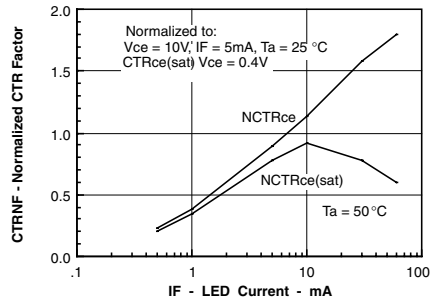


Figure 14. Normalization factor for non-saturated and saturated CTR $T_A=70^\circ\text{C}$ versus I_F

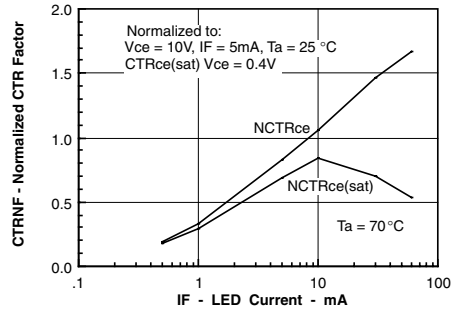


Figure 15. Normalization factor for non-saturated and saturated CTR $T_A=100^\circ\text{C}$ versus I_F

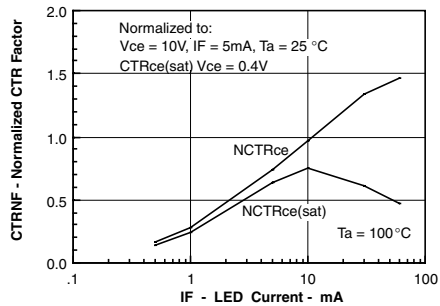


Figure 16. Peak LED current versus pulse duration, τ

